# NEC'S WIDE BAND SINGLE CONTROL CMOS SPDT SWITCH

#### **FEATURES**

- SUPPLY VOLTAGE : 1.8 to 3.3 V (2.8 V TYP.)
- SINGLE SWITCH CONTROL VOLTAGE: Vcont (H) = 1.8 to 3.3 V (2.8 V TYP.) Vcont (L) = -0.2 to +0.2 V (0 V TYP.)
- LOW INSERTION LOSS:
   0.6 dB TYP. @ DC to 1.0 GHz
   0.8 dB TYP. @ 1.0 to 2.0 GHz
   0.95 dB TYP. @ 2.0 to 2.5 GHz
- HIGH ISOLATION: 32.5 dB TYP. @ DC to 1.0 GHz 25 dB TYP. @ 1.0 to 2.0 GHz

25 dB TYP. @ 1.0 to 2.0 GHz 22.5 dB TYP. @ 2.0 to 2.5 GHz

- POWER HANDLING: Pin (0.1 dB) = +17.0 dBm TYP. @ 1.0GHz, VDD = 2.8 V Pin (1 dB) = +21.0 dBm TYP. @ 1.0 GHz, VDD = 2.8 V
- HIGH-DENSITY SURFACE MOUNT PACKAGE: 6-pin minimold package (1.5 × 1.1 × 0.55 mm)
- Pb-FREE

## DESCRIPTION

NEC's UPD5710TK is a wide-band single control CMOS MMIC SPDT (Single Pole Double Throw) switch for mobile communications, instrumentation, short range wireless, and general-purpose RF switching applications.

This device can operate from DC to 2.5GHz with low insertion loss and high isolation, and generally does not require blocking capacitors on the RF lines.

The UPD5710TK is housed in a Pb-Free 6-pin minimold (1511) package, suitable for high-density surface mounting.

## **APPLICATIONS**

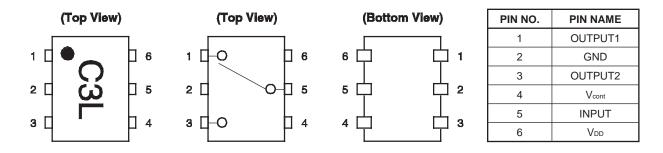
- MOBILE COMMUNICATIONS
- SET TOP BOXES
- SHORT RANGE WIRELESS
- INSTRUMENTATION

## ORDERING INFORMATION

PART NUMBER	PACKAGE	MARKING	SUPPLYING FORM
μPD5710TK-E2-A	6-pinlead-less minimold (1511)	C3L	<ul> <li>Embossed tape 8 mm wide</li> <li>Pin 1, 6 face the perforation side of the tape</li> <li>Qty 5 kpcs/reel</li> </ul>

**Remark** To order evaluation samples, contact your nearby sales office. Part number for sample order: UPD5710TK

#### PIN CONNECTIONS AND INTERNAL BLOCK DIAGRAM



#### TRUTH TABLE

VCONT	INPUT-OUTPUT1	INPUT-OUTPUT2		
Low	OFF	ON		
High	ON	OFF		

#### ABSOLUTE MAXIMUM RATINGS (TA =+25°C, unless otherwise specified)

PARAMETER	SYMBOL	RATINGS	UNIT
Supply Voltage	Vdd	+4.6	V
Switch Control Voltage	Vcont	+4.6	V
Continuous Current	Idc	60	mA
Input Power	Pin	+27	dBm
Operating Ambient Temperature	TA	-45 to +85	°C
Storage Temperature	Tstg	-65 to +150	°C

## RECOMMENDED OPERATING RANGE (TA =+25°C, unless otherwise specified)

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT
Supply Voltage	Vdd	+1.8	+2.8	+3.3	V
Switch Control Voltage (H)	Vcont (H)	+1.8	+2.8	+3.3	V
Switch Control Voltage (L)	Vcont (L)	-0.2	0	+0.2	V

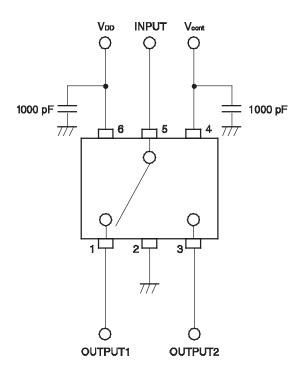
**Notes 1.**  $|V_{cont(H)} - V_{cont(L)}| \le 0.1 V$ 

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Insertion Loss 1	Lins1	f = DC to 1.0 GHz	-	0.6	0.8	dB
Insertion Loss 2	Lins2	f = 1.0 to 2.0 GHz	-	0.8	1.0	dB
Insertion Loss 3	Lins3	f = 2.0 to 2.5 GHz	-	0.95	1.2	dB
Isolation 1	ISL1	f = DC to 1.0 GHz	30	32.5	-	dB
Isolation 2	ISL2	f = 1.0 to 2.0 GHz	22	25	-	dB
Isolation 3	ISL3	f = 2.0 to 2.5 GHz	-	22.5	-	dB
Input Return Loss	RLin	f = DC to 2.5 GHz	15	20	-	dB
Output Return Loss	RLout	f = DC to 2.5 GHz	15	20	-	dB
0.1 dB Loss Compression Input Power Note	Pin (0.1 dB)	f = 1.0 GHz	+13.5	+17.0	-	dBm
1 dB Loss Compression Input Power Note	Pin (1 dB)	f = 1.0 GHz	-	+21.0	-	dBm
Intermodulation Intercept Point	IIP3	2 tone, 1.000/1.001GHz, 1 MHz spacing	-	+33	-	dBm
Supply Current	lod	No RF	-	0.01	1.0	μΑ
Switch Control Current	Icont	No RF	-	0.01	1.0	μΑ
Switch Control Speed	tsw		-	30	500	ns

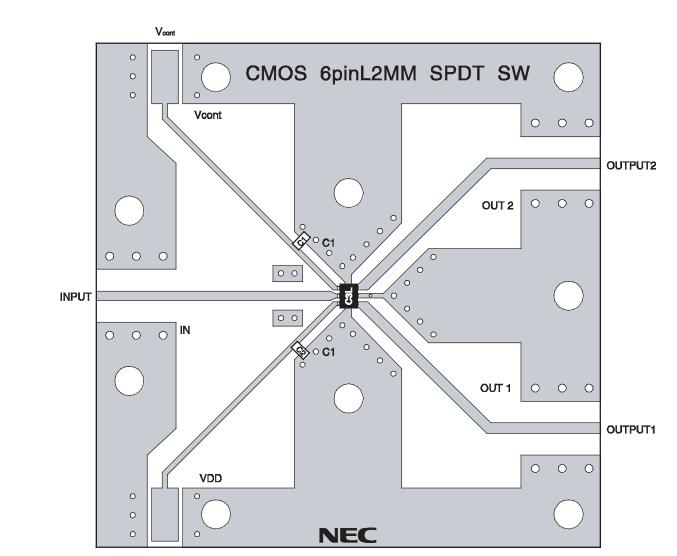
ELECTRICAL CHARACTERISTICS (TA = +25°C, VDD = 2.8V, Vcont(H) = 2.8 V, Vcont(L) = 0 V, unless otherwise specified)

**Notes**. Pin (0.1 dB) or Pin (1 dB) are the measured input power level when the insertion loss increases 0.1 dB more or 1dB than that of linear range.

## **EVALUATION CIRCUIT**



The application circuits and their parameters are for reference only and are not intended for use in actual design-ins.



## ILLUSTRATION OF THE TEST CIRCUIT ASSEMBLED ON EVALUATION BOARD

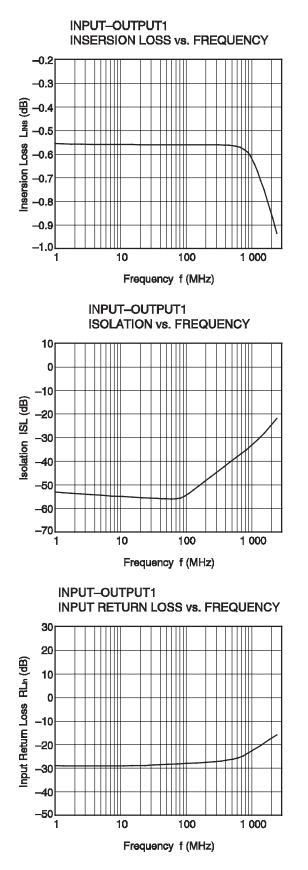
Vdd

## USING THE NEC EVALUATION BOARD

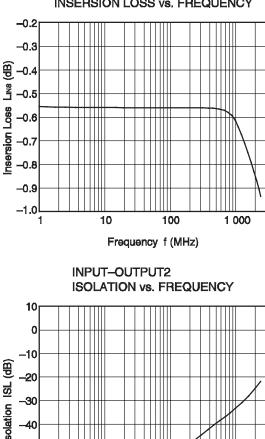
SYMBOL	VALUES		
C1, C2	1,000 pF		

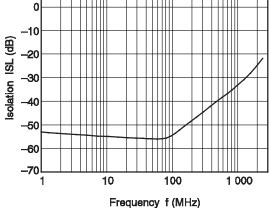
#### **TYPICAL CHARACTERISTIC**

(TA = +25°C, VDD = 2.8 V, Vcont (H) = 2.8 V, Vcont (L) = 0 V, unless otherwise specified)

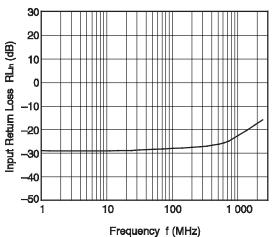


Remark The graphs indicate nominal characteristics.





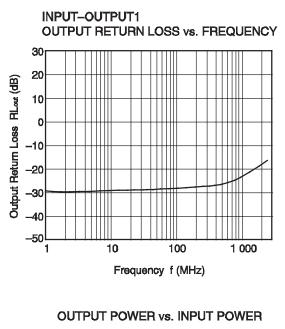
INPUT-OUTPUT2 **INPUT RETURN LOSS vs. FREQUENCY** 

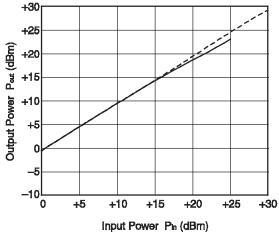


**INPUT-OUTPUT2 INSERSION LOSS vs. FREQUENCY** 

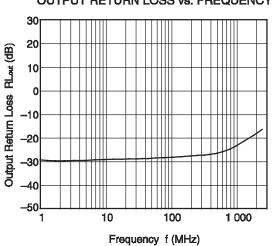
#### **TYPICAL CHARACTERISTIC**

(TA = +25°C, VDD = 2.8 V, Vcont (H) = 2.8 V, Vcont (L) = 0 V, unless otherwise specified)





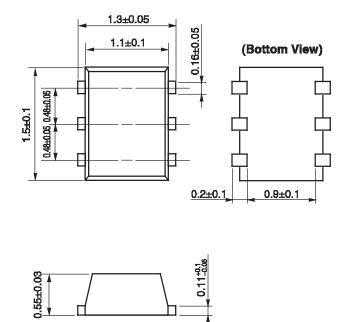
**Remark** The graphs indicate nominal characteristics.



INPUT-OUTPUT2 OUTPUT RETURN LOSS vs. FREQUENCY

## PACKAGE DIMENSIONS

## 6-PIN LEAD-LESS MINIMOLD (1511) (UNIT:mm)



## **RECOMMENDED SOLDERING CONDITIONS**

This product should be soldered and mounted under the following recommended conditions. For soldering methods and conditions other than those recommended below, contact your nearby sales office.

Soldering Method	Soldering Conditions	Condition Symbol	
Infrared Reflow	Peak temperature (package surface temperature)	: 260°C or below	IR260
	Time at peak temperature	: 10 seconds or less	
	Time at temperature of 220°C or higher	: 60 seconds or less	
	Preheating time at 120 to 180°C	: 120±30 seconds	
	Maximum number of reflow processes	: 3 times	
	Maximum chlorine content of rosin flux (% mass)	: 0.2%(Wt.) or below	
VPS	Peak temperature (package surface temperature)	: 215°C or below	VP215
	Time at temperature of 200°C or higher	: 25 to 40 seconds	
	Preheating time at 120 to 150°C	: 30 to 60 seconds	
	Maximum number of reflow processes	: 3 times	
	Maximum chlorine content of rosin flux (% mass)	: 0.2%(Wt.) or below	
Wave Soldering	Peak temperature (molten solder temperature)	: 260°C or below	WS260
	Time at peak temperature	: 10 seconds or less	
	Preheating temperature (package surface temperature)	: 120°C or below	
	Maximum number of flow processes	: 1 time	
	Maximum chlorine content of rosin flux (% mass)	: 0.2%(Wt.) or below	
Partial Heating	Peak temperature (pin temperature)	: 350°C or below	HS350
	Soldering time (per side of device)	: 3 seconds or less	
	Maximum chlorine content of rosin flux (% mass)	: 0.2%(Wt.) or below	

Caution Do not use different soldering methods together (except for partial heating).

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